



SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT BY APPLICANT - PTO FORM 1449	Atty Docket No 10191/2197	Serial No 10/030,309
	Applicant(s) Alfred GOERLACH	
	Filing Date May 13, 2002	Group 2814

U. S. PATENT DOCUMENTS

EXAMINER INITIAL	PATENT NUMBER	PATENT DATE	NAME	CLASS	SUBCLASS	FILING DATE

FOREIGN PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB- CLASS	TRANSLATION	
						YES	NO
DF	197 05 728	August 20, 1998	DE				
DF	08264811	October 11, 1996	JP				

OTHER DOCUMENTS

EXAMINER INITIAL	AUTHOR, TITLE, DATE, PERTINENT PAGES, ETC.
DF	K. J. Schoen et al., "High Voltage GaInP/GaAs Dual Material Schottky Rectifiers," Appl. Phys. Lett. Vol. 71, No. 4, pp. 518 to 520, July 28, 1997

EXAMINER <i>Don Shan</i>	DATE CONSIDERED 6/23/02
EXAMINER: Initial if citation considered, whether or not citation is in conformance with M.P.E.P. 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant	